Dual PLL frequency synthesizer BU2630F / BU2630FV

The BU2630F/BU2630FV are a CMOS LSI with an internal dual PLL synthesizer.

VCOs for transmission and reception can be controlled independently, and the reference frequency and main counter settings can also be programmed separately. This product is designed for applications involving cordless telephones and communications equipment worldwide.

Applications

Cordless telephones, amateur short wave radios, industrial transceivers, VHF/UHF frequency generators, and others

Features

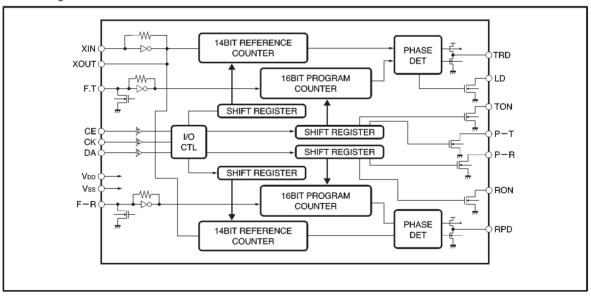
- 1) Operation possible at up to 80MHz ($V_{DD} = 2.5$).
- 2) Low current dissipation

Dual-system operation : 2.2mA (typ), $V_{DD} = 3V$ Single-system operation : 1.2mA (typ), $V_{DD} = 3V$

Non-operating state : 0.2mA (typ), $V_{DD} = 3V$

- 3) 16-bit main counter.
- 4) Internal 14-bit reference frequency counter.
- 5) Unlock detection possible.
- 6) Four output ports. (open drain)
- 7) Control possible using 3-wire serial input.

Block diagram



● Absolute maximum ratings (Ta = 25°C)

Param	eter	Symbol	Limits	Unit
Power supply voltag	је	V _{DD}	−0.3∼+7.0	V
Device dissination	BU2630F	D4	500*1	
Power dissipation	BU2630FV	Pd	350* ²	mW
Operating temperat	ure	Topr	−40~+85	Ĉ
Storage temperatur	е	Tstg	−55 ~ +125	ొ

^{*1} Reduced by 5.0mW for each increase in Ta of 1°C over 25°C.

●Recommended operating conditions (Ta = 25°C)

Parameter	Symbol	Min.	Тур.	Max.	Unit
Power supply voltage	V _{DD}	2.5	3.0	5.5	٧

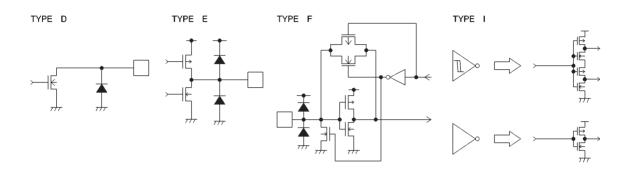
Pin descriptions

Pin No.	Pin name	Name	Function	I/O cuircuit
16	XOUT	Cristal reconstan	Converte veneral fragularity	TYPE A
1	XIN	Crystal resonator	For reference frequency	TYPEA
2	Vss			
3	RPD	Phase comparator output	This is LO if the locally divided value is higher than the reference frequency, HI if it is lower, and Z if it matches.	TYPE E
4	P-R	Output nort	This is controlled by the input date	TYPE D
5	RON	Output port	This is controlled by the input data.	TYPED
6	F-R	VCO input	Local input for reception	TYPE F
7	CE	Chip enable		
8	CK	clock signal	When CE is HIGH, the DA synchronized to the rise of CK is read into the internal shift register, and is latched at the timing of the CE fall.	TYPE B
9	DA	serial data	into the internal shift register, and is fatoried at the tilling of the OL fail.	
10	LD	Unlock output	This goes ON when the PLL is unlocked on the transmission side	TYPE D
11	F-T	VCO input	Local input for transmission	TYPE F
12	TON	•		7.07
13	P-T	Output port	This is controlled by the input data	TYPE D
14	TPD	Phase comparator output	This is LO if the locally divided value is higher than the reference frequency, HI if it is lower, and Z if it matches.	TYPE E
15	V _{DD}	Power supply	2.5~5.5V	

^{*2} Reduced by 3.5mW for each increase in Ta of 1°C over 25°C.

●Input/output circuits

TYPE A TYPE B TYPE C



●Electrical characteristics (unless otherwise noted, Ta = 25°C, V_{DD} = 3.0V, V_{SS} = 0V)

Parameter	Symbol	Min.	Тур.	Max.	Unit	Co	enditions
Power supply current 1	I _{DD1}	_	2.2	3.0	mA	Dual-system operation	F-TF-R=80MHz, 100mVrms
Power supply current 2	I _{DD2}	_	1.2	2.0	mA	Single-system operation	XTAL=10.24MHz
Power supply current 3	IDD3	_	0.2	0.3	mA	With operation stopped:	XTAL = 10.24 MHz
Input high level voltage 1	VIH1	0.8V _{DD}	_	_	٧	CE CK DA	
Input low level voltage 1	V _{IL1}	_	_	0.2V _{DD}	٧	CE CK DA	
Input high level current 1	liH1	_	_	1.0	μA	CE CK DA VIN=VDD	
Input high level current 2	I _{IH2}	-	0.3	_	μA	XIN VIN=VDD	
Input high level current 3	Інз	-	5.0	_	μΑ	F-TF-R VIN=VDD	
Input low level current 1	lıL1	-1.0	_	_	μΑ	CE CK DA VIN=Vss	
Input low level current 2	lıL2	_	-0.3	_	μΑ	XIN V _{IN} =V _{SS}	
Input low level current 3	lıцз	-	-5.0	_	μΑ	F-TF-R VIN=Vss	
Output low level voltage 1	V _{OL1}	-	0.3	0.5	٧	LD TON P-T RON P-F	R lo=1.0mA
Off level leakage current 1	loff1	-	_	1.0	μΑ	LD TON P-T RON P-F	R Vo=10V
Output low level voltage 2	V _{OL2}	-	-	0.3	٧	F-TF-R lout=0.1mA	
Output high level voltage	Vонз	V _{DD} -50	V _{DD} -1.0	_	mV	TPD RPD lout=−0 µA	
Output low level voltage	Vol3	-	1.3	50	mV	TPD RPD louτ=0 μ A	
Output high level voltage	V _{OH4}	V _{DD} -100	V _{DD} -40	-	mV	TPD RPD Iout=-100 µ	Α
Output low level voltage	V _{OL4}	_	30	100	mV	TPD RPD Ιουτ=100 μ A	
Off level leakage current 2	loff2	_	-	100	nA	TPD RPD Vout=VDD	
Off level leakage current 3	loff3	-100	_	_	nA	TPD RPD Vout=Vss	
Internal feedback resistance 1	RF1	_	10	_	МΩ	XIN	
Internal feedback resistance 2	RF2	_	500	_	kΩ	F-TF-R	
Input frequency 1	F _{IN1}	1.0	10.24	16.0	MHz	XIN, sine wave, C coupl	ing
Input frequency 2	F _{IN2}	1.0	-	20	MHz	F-T F-R, sine wave, C c	oupling*2, VıN = 100 mVrms
Input frequency 3	Fina	50	_	80	MHz	F-T F-R, sine wave, C c	oupling*2, Vın = 100 mVrms
Input frequency 4	FIN4	20	_	50	MHz	F-T F-R, sine wave, C c	oupling*2, V _{IN} = 50 mVrms
Input frequency 5*1	Fin5	0.4	_	20	MHz	F-T F-R, sine wave, C c	oupling*2, V _{IN} =100mVrms
Maximum input amplitude	FINMax.	_	_	V _{DD} + 0.3	V _P -P	XIN, F-TF-R	
Input capacitance	Cin	_	4	7	PF	F-TF-R	
Minimum pulse width	TW	1.0	_	_	μs	CK, DA	
Input data rise time	TR	_	_	300	ns	CK, DA	
Input data fall time	TF	_	_	300	ns	CE, CK, DA	

O Not designed for radiation resistance.

*1 PS = 1

Divider values which can be set

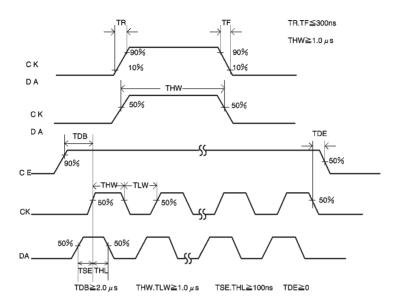
*2 Minimum input level at which operation is possible

Program divider: PS = 0: 256 to 65535, PS = 1: 3 to 4095

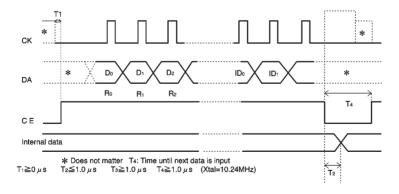
Reference frequency divider: 3 to 16383

Circuit operation

Input data switching characteristics

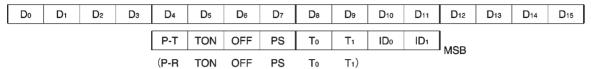


Input data format



Programmable divider and control data input: TX side ($ID_0 = 0$, $ID_1 = 0$), RX side ($ID_0 = 1$, $ID_1 = 0$)

LSB ← Input from D₀



Reference frequency divider data input: TX side ($ID_0 = 0$, $ID_1 = 1$), RX side ($ID_0 = 1$, $ID_1 = 1$)

R₀	R ₁	R ₂	Rз	R ₄	R₅	R ₆	R ₇	Rs	R ₉	R ₁₀	R ₁₁	R ₁₂	R13	PL	PH
LSB				*	*	LD₀	LD ₁	*	*	IDο	ID ₁	MSB			

* Does not matter (LDo and LD10 are valid on TX side only)

Description of data

(1) Programmable divider data: D₀ ~ D₁₅

D₀ Examp	D ₁ le: For a	D ₂	D₃ ission fr	D ₄	D₅ / of 46.6	D ₆ S10MHz	D ₇	D ₈ eference	D ₉	D ₁₀	D ₁₁ .00 kHz	D ₁₂	D ₁₃	D ₁₄	D ₁₅
Example: For a transmission frequency of 46.610MHz and a reference frequency of 5.00 kHz No. of divisions: $46.610 \div 5.00$ kHz = 9322 (D) = $246A$ (H)															
0	1	0	1	0	1	1	0	0	0	1	0	0	1	0	0
i							_	-	-		-	_		-	- ;

(2) Reference frequency data: $R_0 \sim R_{13}$

R₀	Rı	R2	Rз	R4	R5	R ₆	R ₇	Re	R ₉	R10	R11	R ₁₂	R13
						ı					l		l

Example: When XTAL = 10.24 MHz and reference frequency is 5.00 kHz

No. of divisions: 10.24 MHz \div 5.00 kHz = 2048 (D) = 800 (H)

0	0	0	0	0	0	0	0	0	0	0	1	0	0
	(D			()				8		()

- (3) Output port control data: P-T (P-R) TON (RON)
 - 1 : Open drain output ON (LO)
 - 0 : Open drain output OFF (HI)
- (4) OFF transmission side (reception side): Operation stopped

F - T (F - R) pull-down: TPD (RPD) high-impedance, LD = OFF

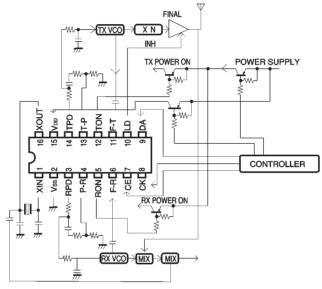
(5) PS

Programmable device change : No. of divisions = $3 \sim 4095$

Do	D ₁	D ₂	Dз	D4	D ₅	D ₆	D ₇	D8	D ₉	D ₁₀	D ₁₁	D ₁₂	D ₁₃	D ₁₄	D15
*	* DON'T	* CARE	*	LSB											MSB

- (6) PL, PH, and PD pin control
 - 0 0: PLL operation
 - 1 0: Forced LO state
 - 0 1: Forced HI state
 - 1 1: Forced LO state
- (7) LD₀, LD₁, LD pin control (valid only on TX side)
 - 0 0: ON when unlocked (LO)
 - 0 1: Air pulse output
 - 1 0: Forced ON state (LO)
 - 1 1: Forced OFF state (HI)
- (8) Input (00) to test T0 and T1.

Application example



*: Immediately after the power supply is turned on, the various pins remain unstable until data is input.

Fig. 1

Electrical characteristic curves

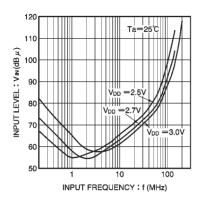


Fig. 2 Input frequency vs. input level

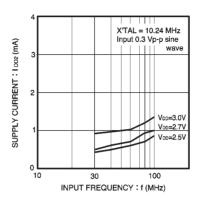


Fig. 3 Input frequency vs. supply current (for single operation)

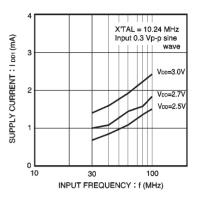
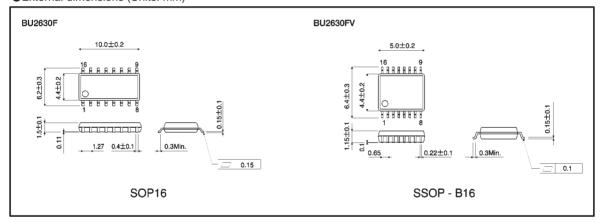


Fig. 4 Input frequency vs. supply current (for dual operation)

●External dimensions (Units: mm)



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